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Solid state engineering of Bi₂S₃/rGO nanostrips: an excellent electrode material for energy storage applications†

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The study presents a novel, one-pot, and scalable solid-state reaction scheme to prepare bismuth sulphide (Bi₂S₃)-reduced graphene oxide (rGO) nanocomposites using bismuth oxide (Bi₂O₃), thiourea (TU), and graphene oxide (GO) as starting materials for energy storage applications. The impact of GO loading concentration on the electrochemical performance of the nanocomposites was investigated. The reaction follows a diffusion substitution pathway, gradually transforming Bi₂O₃ powder into Bi₂S₃ nanostrips, concurrently converting GO into rGO. Enhanced specific capacitances were observed across all nanocomposite samples, with the Bi₂S₃@0.2rGO exhibiting the highest specific capacitance of 705 F g⁻¹ at a current density of 1 A g⁻¹ and maintaining a capacitance retention of 82% after 1000 cycles. The superior specific capacitance is attributed to the excellent homogeneity and synergistic relation between rGO and Bi₂S₃ nanostrips. This methodology holds promise for extending the synthesis of other chalcogenides-rGO nanocomposites.

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1. Introduction

Currently, energy and environmental-related challenges capture global attention. To address the growing need for energy storage, considerable research efforts have been directed toward the development and usage of Lithium-ion batteries (LIB), fuel cells (FC), and supercapacitors (SC).^{1–3} SCs are distinct either from the traditional capacitors or batteries, capable of delivering higher power density, speedy charging, and relatively longer life-span riveting them as suitable candidates for a variety of energy storage applications.^{4–10}

The selection of electrode material for SC depends on the type of application in hand and often involves a trade-off between factors such as specific capacitance, energy density, and the cost of material synthesis and processing. Metal sulphides have emerged as a prominent class of SC material compared to the metal oxides due to their, (i) higher electronic conductivity (arising from the lower electronegativity of S-atom) allowing faster electron transfer during the charging–

discharging cycles, (ii) larger pseudocapacitance (due to the reversible faradaic redox-reaction) behaviour that provides additional capacitive storage of energy, (iii) better cycling stability which leads to the long-term reliability, and (iv) higher energy density offering faster storage and release of energy for suitable application.¹¹ To date, many metal-sulphides (metal = Co, Ni, Mo, Cu, Bi, *etc.*) are reported to have SC properties.^{12–16} Bismuth sulphide (Bi₂S₃) is one of the most versatile materials on the list having diverse applications in LIBs, SC, photocatalysis, and electrochemical conversion reaction.^{17–20}

Several synthesis methods have been developed to produce nanostructured Bi₂S₃ materials including chemical vapor deposition (CVD), hydrothermal/solvothermal methods, template-directed procedures, and organometallic complex precursor decomposition techniques.^{21–24} To guarantee effective electron transport through the material (as required for SC application), researchers often design Bi₂S₃ nanocomposite systems mixed with carbon-based conducting substances.^{25–30} In contrast to the aforementioned synthesis approaches, a cost-effective method for large-scale material preparation must adhere to the solid-state route. Keeping the requirements for SC application in mind, herein, we have developed a one-pot solid-state reaction scheme to prepare Bi₂S₃@rGO nanocomposite materials from bismuth oxide (Bi₂O₃), thiourea (TU), and graphene oxide (GO) as the starting materials. The reaction scheme can be understood as a diffusion-substitution mechanism resulting in phase pure bismuth-sulphide nanomaterials. It is important to mention here that, the amount of GO used in this

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study is significantly lesser compared to the other reports.^{7,27} During the course of solid–solid phase transformation (from Bi₂O₃ to Bi₂S₃) with excess TU, the simultaneous reduction of GO to rGO increases both the electrochemical surface area and the contact region between Bi₂S₃ and rGO, in the nanocomposite. We showcase the characterization of the materials and then present the specific capacitance results of the nanocomposite materials and compare these values with both the pristine Bi₂S₃ sample and those reported by others.

2. Experimental

2.1. Materials

Analytical grade bismuth oxide (Bi₂O₃, BO), thiourea (CH₄N₂S, TU), potassium hydroxide (KOH), and graphene oxide (GO) powders were procured from Fisher Scientific and were used as received without further purification. Nickel foam, Ag/AgCl electrodes, and Pt-wire electrodes were purchased from Global Nanotech Company (Mumbai, India). Deionized water obtained from the Millipore water purification plant was used as a solvent throughout the synthesis process.

2.2. One-pot solid-state synthesis of pristine Bi₂S₃

Pristine Bi₂S₃ powder was synthesized by a simple solid-state transformation of a one-pot mixture of BO and TU at sufficiently lower temperatures. In a typical method, the calculated amount of BO and TU powders were thoroughly mixed in an agar mortar and ground well for 15 min before being transferred into a porcelain crucible. Next, the crucible was covered with a porcelain lid and heat-treated at 140 °C in a hot-air oven. The precursor's amount, reaction temperatures, and reaction times were varied for the optimization of the synthesis process.

2.3. Design of experiment and optimization of reaction parameters

The effect of the three process parameters namely, reaction temperature (*A*), reaction time (*B*), and precursors ratio (*C*), on the phase purity of the pristine Bi₂S₃ phase and thereby optimizing the same, was studied using response surface methodology (RSM). We used a central composite design (CCD) technique with three-factors (*A*, *B*, and *C*) and three-levels (−1, 0, and 1) classification which resulted in a total of 20 reaction trials, as formulated by design expert 13, tabulated in the Table S1, in the ESI.† Each sample was then examined for phase purity by XRD which was designated as the response (*Y*). In cases, where the phase pure Bi₂S₃ was obtained we labelled the response as 1, otherwise, we marked it as 0. All the responses are populated in Table S1.† A second-order polynomial equation was considered to fit the CCD results.

$$Y_{\text{response}} = \beta_0 + \beta_1 A + \beta_2 B + \beta_3 C + \beta_{12} AB + \beta_{23} BC + \beta_{13} AC + \beta_{11} A^2 + \beta_{22} B^2 + \beta_{33} C^2 \quad (1)$$

In the above equation, β_0 represents the regression coefficient, β_i is the linear coefficient, β_{ii} represents the quadratic coefficient, and β_{ij} denotes the interaction coefficient ($i, j = 1, 2,$

3). *A*, *B*, and *C* are the coded values of the parameters. Analysis of variance (ANOVA) for the chosen model was examined and finally, the optimization tests were performed.

2.3.1 One-pot solid-state synthesis of Bi₂S₃@rGO nanocomposite. After optimizing the solid-state reaction conditions for the one-pot synthesis of pristine Bi₂S₃, we use the same reaction procedure and synthesis parameters (*e.g.*, temperature, time, and BO to TU molar ratio) for the one-pot synthesis of Bi₂S₃@rGO nanocomposites. In this case, we have also varied the weight % (0.2, 0.4, and 0.8) of GO powder in the starting reaction mixture with respect to the BO powder. In a typical one-pot procedure (see Fig. 1), 2.7 g of BO and 2.6 g of TU were mixed (1 : 6 mol ratio) thoroughly with calculated amount of GO powders in an agar mortar and transferred into a porcelain crucible to put into a hot-air oven at 140 °C for 16 h. After completion of the reaction, the final product was washed carefully with distilled water and ethanol several times. Finally, the reaction products were dried at 100 °C overnight in a vacuum oven to obtain the final nanocomposite powders. As a control experiment, GO and TU powders were mixed (with a 1 : 6 mol ratio) and similarly heat-treated at 140 °C for 16 h.

2.4. Characterization

The thermochemistry of the solid–solid reaction was monitored by Differential Scanning Calorimetry (DSC Q10 V9.9 Build303, US instrument) in a temperature range of 30–300 °C with a ramp rate of 5° per min in air. The phase analyses of the synthesized samples were performed by X-ray diffractometer (XRD-D8, Advance, Bruker-AXS) using Cu-K α radiation ($\lambda = 1.5418 \text{ \AA}$) in the 2θ range of 10–80° with step size 0.02. Surface morphology analyses and microstructural study of the samples were performed using Field Emission Scanning Electron Microscopy (FESEM; Hitachi, S-4800 II) and Transmission Electron Microscopy (TEM; FE-TEM Philips EM-CM-12) at an operating voltage of 5 kV and 200 kV, respectively. Laser Raman spectroscopy was carried out using a Lab RAM HR800 from JY Horiba equipped with a 532 nm He–Ne Laser radiation. All electrochemical measurements were performed by Auto Lab (model PGSTAT 30, eco-chemie) work station.

2.5. Electrochemical measurement

The electrochemical properties of the pristine and the nanocomposite samples were investigated using a three-electrode cell configuration in the 6 M KOH aqueous electrolyte



Fig. 1 Schematic of the one-pot solid-state synthesis process.



solution. In each case, the sample material was used as the working electrode while, Ag/AgCl electrode was used as the reference electrode and platinum wire as the counter electrode. The working electrode was prepared by mixing the prepared sample with acetylene black and polyvinylidene fluoride in a mass ratio of 8 : 1 : 1, blended with a few drops of *N*-methyl-2-pyrrolidone. The slurry mixture was then coated onto the Ni-foam (NF) substrate. Finally, the as-fabricated electrode was left to vacuum dry in an oven at 80 °C for 24 h. The mass loading density of the active material in all electrodes was calculated using weight difference method and found about 1–1.5 mg cm⁻². A potential window ranging from -0.2 to -0.85 was chosen for the cyclic voltammetry (CV) measurements and galvanometric charge–discharge tests. The electrochemical impedance spectroscopy (EIS) measurements were conducted over a frequency range of 0.01 Hz to 100 kHz with an AC potential amplitude of 5 mV. All electrochemical characterizations were conducted under room temperature conditions.

3. Results & discussion

3.1. Optimization of pristine Bi₂S₃ synthesis parameters using response surface methodology

Each of the 20 samples obtained from the CCD trial runs was thoroughly analysed by XRD to identify the crystallographic phases present in the final products. The obtained diffraction patterns are compared with the standard JCPDS files using X'Pert High Score Plus software. The detailed design of experiments, analysis of variance (ANOVA) test, and optimization of solutions were shown in the ESI, Section S1.† From Table S1,† the formation of phase pure Bi₂S₃ phase was detected in the trial run 1, 11, 18, and 20. Multiple regression models were tried to perform the ANOVA tests and a quadratic polynomial model was selected for accurately describing our experimental results. The estimated values obtained from the model fitting are summarized in Table S2.† From Table S2,† the obtained model *F*-value of 71.34 implies the model is significant and the *P*-values less than 0.0500 indicate the model terms (in this case *A*, *C*, *AC*, *A*², and *C*²) are important. The fit statistics are displayed in Table S3, in the ESI (ESI)† indicating the predicted *R*² of 0.8840 is in reasonable agreement with the adjusted *R*² of 0.9709. Fig. S1a† shows the normalised probability plot of the studentized residuals and Fig. S1b† shows the correlation between the predicted and actual values of the response. Fig. S2† shows various interaction effects among the process parameters using a 3D surface plot, where one of the parameters is fixed at a particular value while the other two are allowed to vary. From the curvature of the surface plots presented in Fig. S2,† it is concluded that the interaction between temperature (*A*) and precursors ratio (*C*) is the most vital of all. Optimized calculation (a list of constraints for the optimization method is given in Table S4, in the ESI†) has predicted a total of 100 possible solutions for the reaction parameters, as described in Table S5, in the ESI.† From Table S5,† the most significant of them was selected as the best conditions for the phase pure Bi₂S₃ synthesis, which are ~140 °C temperature, ~13 h reaction time, and ~1 : 6 BO to TU molar ratio.

3.2. Formation of pristine Bi₂S₃ from Bi₂O₃ precursor using XRD and DSC studies

The conversion of the BO phase into the Bi₂S₃ phase in the presence of TU using solid-state reaction is involved at a temperature below the melting points of both components. The precursor BO powder was first thoroughly analysed by XRD technique (Fig. S3, in the ESI†). Two different polymorphs of BO, such as alpha (monoclinic type) and beta (cubic type) were identified by X'Pert High Score Plus software. The whole XRD profile was then refined by the Rietveld method to quantify corresponding phases and to analyze their crystal lattice structures (Fig. S3, in ESI†). A major portion of the alpha phase (91.2%) with a small amount of beta (8.8%) phase was measured. From the refinement, a considerable amount of deficiency in the oxygen site occupancy factors was found for the BO powder. The solid–solid reaction between the precursor powders can be highly complex with the possibility for multiple dynamical components operating at the same time. It is known that imperfection in the host crystal lattice facilitates the diffusion of incoming ions/molecules during the solid-state reaction. To understand the effect of heat treatment, we have performed a DSC study of the powder mixture in the temperature range 30–300 °C, as shown in Fig. 2. The broad endothermic valley in the temperature range 30–100 °C, signifies the loss of water molecules and/or volatile compounds physisorbed to the precursor powders. TU starts decomposing at a temperature range of 120–140 °C into an active sulphidation agent (H₂S) and cyanamide (NH₂CN) according to eqn (2). We posited that the presence of excess TU in the synthetic melt of BO-TU probably lowers the melting temperature of TU by forming a eutectic mixture.³¹ The *in situ* formed sulphur source is then diffused through the solid BO particulates and results in solid–solid phase transition (from monoclinic BO to orthorhombic Bi₂S₃, according to eqn (3)) at a temperature range of 120–140 °C, detected as a broad exothermic peak in the DSC measurement. This is followed by the elimination of gaseous cyanamide molecules which are detected as an endothermic peak at 140–160 °C. Above 180 °C, the excess unreacted TU started melting which was captured as a strong endothermic peak at 180–220 °C in the corresponding DSC spectrum.

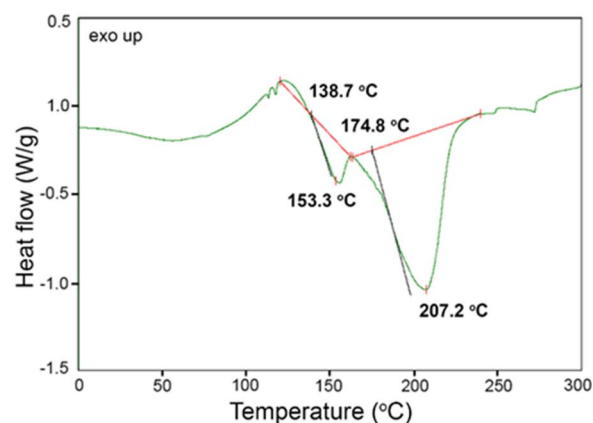
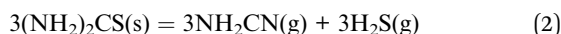


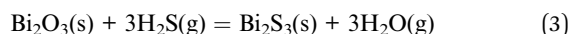
Fig. 2 Differential scanning calorimetry (DSC) curve of BO-TU mixed powder.



The reactions are summarized as follows, Decomposition of TU:



Phase transition:



3.3. Crystal structure study of the Bi_2S_3 @rGO nanocomposite

The XRD patterns of the nanocomposite samples synthesized with different rGO content (0.2, 0.4, and 0.8 wt%) are shown in Fig. 3. All the diffraction peaks are well matched with the orthorhombic Bi_2S_3 phase (space group, $Pbnm$) against the JCPDS card No. 00-043-1471. The XRD signal of rGO is overwhelmed by the presence of highly crystalline Bi_2S_3 peaks and hence remains undetected. However, by analyzing the XRD profile and Raman spectra of the sample (Fig. S4a and b, in the ESI†) we concluded that thiourea can reduce GO into rGO at the chosen experimental conditions. A noticeable fact we observed in the XRD patterns for the nanocomposite samples is that the relative intensity of the (021) plane keeps increasing with an increase in the GO content.

The electrochemical measurements of the pristine Bi_2S_3 sample and all the as-synthesized Bi_2S_3 @rGO nanocomposite were performed (results are shown in the ESI, see Fig. S5 and S6†). Comparing the results, we observed that all the nanocomposite samples show enhanced electrochemical performance for the pristine sample (288 F g^{-1} at 1 A g^{-1}), particularly, the 0.2% sample (designated as Bi_2S_3 @0.2rGO) shows the best values amongst the all. Therefore, we have carefully characterized and compared the Bi_2S_3 @0.2rGO nanocomposite sample with pristine Bi_2S_3 , henceforth, in the manuscript. Fig. 4 shows the Rietveld crystal structure

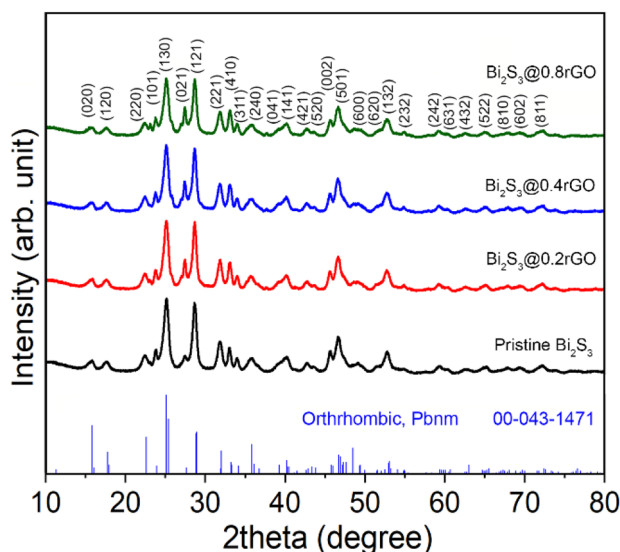


Fig. 3 XRD patterns of the pristine Bi_2S_3 and Bi_2S_3 @rGO nanocomposite samples.

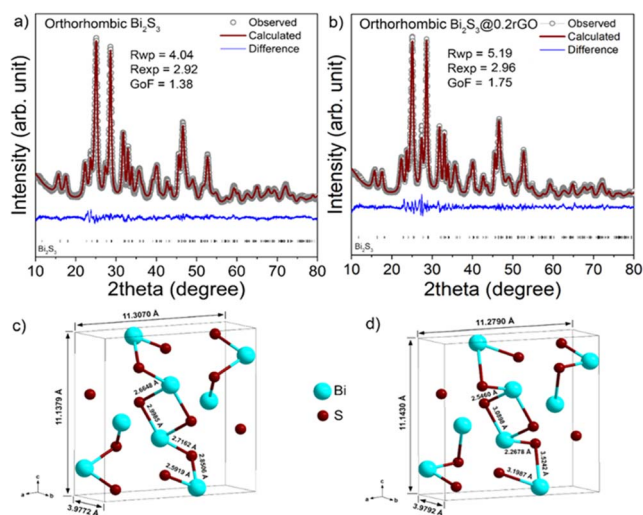


Fig. 4 XRD Rietveld refinement analyses of (a) pristine Bi_2S_3 and (b) Bi_2S_3 @0.2rGO nanocomposite with corresponding refined unit cell representation in (c) and (d), respectively. Different Bi–S bond lengths are shown within corresponding lattice images.

refinement analyses (using MAUD³²) of the two samples. In the refinement, Figure circles represent experimental points while the solid line represents Rietveld refined data. The reliability parameters (R_{wp} , R_{exp} , and GoF) for the fitting analyses are shown in the insets.

The resulting refined process achieved a very good match between the computed and observed patterns. The anisotropic size-strain model as proposed by Popa *et al.*³³ was considered for fitting the microstructural properties of the Bi_2S_3 @0.2rGO nanocomposite sample.³³ The step-wise refined parameters are as follows, (1) background and scale parameters, (2) basic phase parameters, (3) microstructure (anisotropic size and strain), and (4) crystal structure (lattice parameters, occupancy, atomic coordinate, and isotropic displacement factors) parameters.

After the refinements, the crystallography information files (CIF) were generated from MAUD and imported into 'Diamond' software to visualize the refined crystal lattices. The metal–oxygen bond lengths were calculated and shown in Fig. 4c and d along with the two refined crystal lattices (orthorhombic, Space group: $Pnma$). A slight increase in the crystal lattice parameters and considerable changes in the Bi–S bond lengths were measured in the Bi_2S_3 @0.2rGO nanocomposite.

3.4. Morphological study by FESEM and TEM

FESEM images of the precursor BO powder, the pristine Bi_2S_3 , and the Bi_2S_3 @0.2rGO nanocomposite samples are shown in Fig. 5. From the images (Fig. 5a and b) it is observed that the precursor BO powder has an arbitrary morphology with no specific size and shape.

After the solid-state reaction, the pristine Bi_2S_3 powder shows a slightly elongated, rod-like morphology (Fig. 5c and d).

While, the Bi_2S_3 @0.2rGO nanocomposite sample shows 2D nanostrip-like morphology (Fig. 5e and f). No separate rGO sheets are observed in the FESEM.



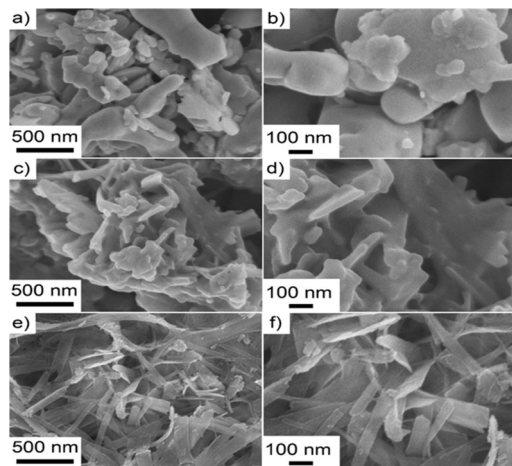


Fig. 5 FESEM images of (a) and (b) precursor BO powder, (c) and (d) pristine Bi_2S_3 , and (e) and (f) $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite samples.

The structural and microstructural analyses of the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample were further carried out by TEM and HRTEM respectively, as shown in Fig. 6. Fig. 6a shows the typical TEM image of the starting GO powder while Fig. 6b shows the aggregated structure of the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample. The sheet-like material covering the particulates is considered as rGO. 2D-nanostrip morphology of Bi_2S_3 is visible in Fig. 6c.

A typical twisted Bi_2S_3 nanostrip is shown in the upper part of Fig. 6d. The HRTEM image of the nanostrips shows the single crystalline nature of the sample and the periodic arrangement of lattice fringes parallel to the growth axis, suggesting the nano-strip has [001] directional growth. Line profile analysis of the selected area of the nanostrip shown in the lower part of Fig. 6d was performed with the help of ImageJ software showing an average interplaner distance (Δd) of 0.36 nm, which corresponds to the (130) plane of orthorhombic Bi_2S_3 . EDS elemental analyses were also performed for the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample, as shown in Fig. 6e–h. Characteristic signals for Bi, S, and C were detected which were then mapped separately. The signal of carbon is detected due to the presence of rGO in the sample and from the background carbon film as well.

Based on the above discussion, we proposed the plausible growth mechanism of the Bi_2S_3 nanostrips in Fig. 6i. At first, BO, GO, and TU form an intimate physical mixture at room temperature upon grinding. The powder mixture was then heat treated at 140 °C for 16 h in an electric oven resulting in the formation of dark greyish nanocomposite powder. TU decomposes at this temperature range into H_2S and acts as a fairly strong reducing agent, as well as the source of sulphur. The *in situ* generated sulphur source then diffuses through the solid BO particulates under a constant inward flux and results in solid–solid phase transition (from monoclinic BO to orthorhombic Bi_2S_3) and at the same time it reduces the oxygen-containing functionalities of GO to form rGO. Nucleation of layered Bi_2S_3 material starts from the surface of the solid particulate and as it grows according to the Wolf's construction of the orthorhombic crystal habit, anisotropic Bi_2S_3 nanostrips

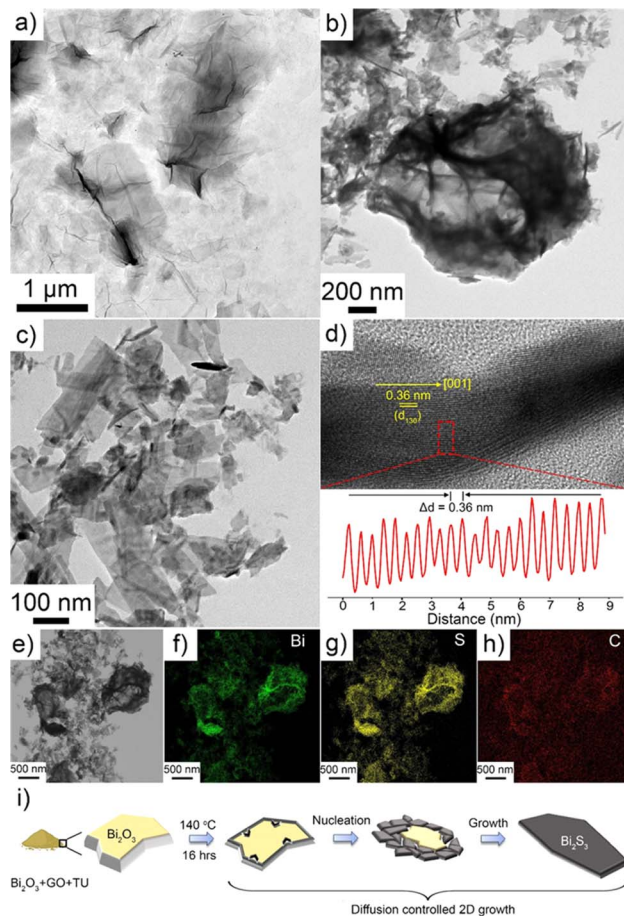


Fig. 6 (a) TEM micrograph of a precursor GO nanosheet. (b) and (c) TEM images of the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample showing an rGO sheet decorated with Bi_2S_3 nanostrips. (d) HR-TEM image with lattice fringes. (e–h) corresponding elemental mapping of C, Bi, and S. (i) Plausible growth mechanism of the 2D Bi_2S_3 nanostrips.

are formed. Mechanism-wise, the present scheme can be considered a diffusion-controlled 2D sacrificial growth process as reported earlier.

3.5. Raman study

Raman spectra for the pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite samples were recorded at room temperature in the range of 500–3000 cm^{-1} and are shown in Fig. 7. The D-band at 1335 cm^{-1} and the G-band at 1596 cm^{-1} of carbon-related material are visible in the Raman spectra of the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite.³⁴

The highly intense peak at $\sim 965\text{ cm}^{-1}$ in the Raman spectrum corresponds to Bi–S stretching vibration³⁵ of the Bi_2S_3 phase. No additional peaks for Bi–O bond vibration corresponding to the Bi_2O_3 phase are detected, which approves the purity of Bi_2S_3 and the as-prepared $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample.

3.6. XPS study

XPS measurements were carried out for the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample to study the chemical nature and oxidation states of various elements present at the surface of the



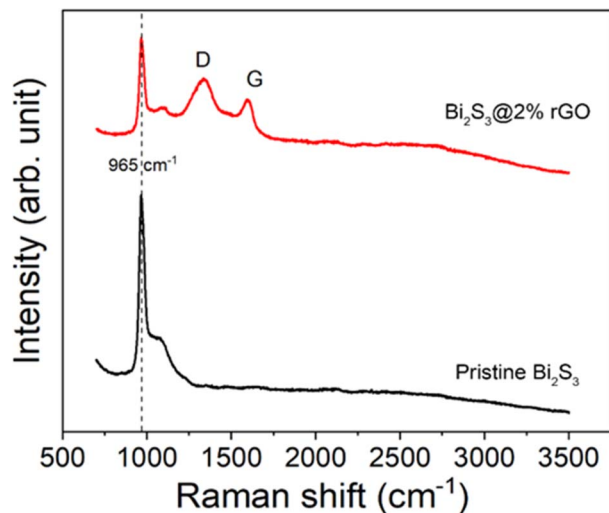


Fig. 7 Raman spectra of the pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite samples.

material. As shown in Fig. 8a, the survey scan demonstrates the presence of C, Bi, S, N, and O elements in the nanocomposite.

The peaks for Bi and S signify the occurrence of the Bi_2S_3 phase while peaks other than Bi and S are responsible for the presence of rGO functionalities in the nanocomposite sample. No characteristic peak for O is detected here, signifying the absence of the Bi_2O_3 phase or any oxygen-functionalities in the nanocomposite sample. High-resolution XPS scans were also performed in the core energy region of C, Bi, and S, as represented in Fig. 8b–d, respectively. Deconvolution of the C core-level spectrum generates peaks corresponding to the C=C and C=N/C–O bonds, which are characteristic of the minute amount of rGO functional moieties present in the sample. Deconvolution of the Bi–S core-level region results in the identification of Bi $4f_{5/2}$ and Bi $4f_{7/2}$ peaks with characteristic

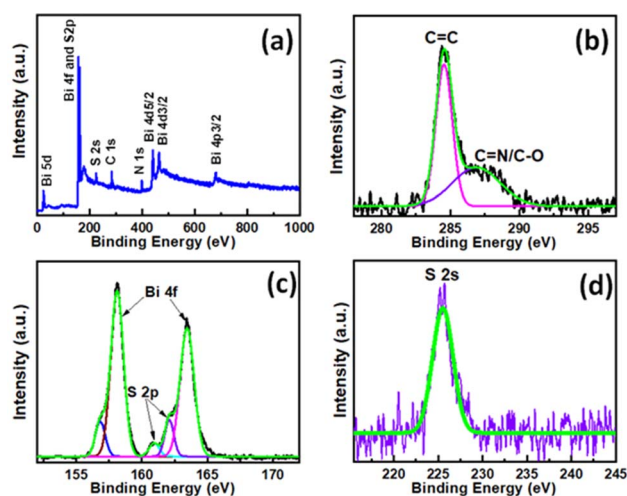


Fig. 8 (a) XPS survey scan of the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample. (b) Core level XPS spectra and deconvolution analyses for (b) C, (c) Bi, and (d) S.

spin–orbit coupling of 5.3 eV, corresponding to the Bi^{3+} ion. This is accompanied by S $2p_{3/2}$ and S $2p_{1/2}$ at 161.0 eV and 162.3 eV, respectively, with characteristic spin–orbit coupling of 2.3 eV, corresponding to the S^{2-} ion. S $2s$ orbital peak was observed at 225.3 eV, corresponding to the S^{2-} ion.

3.7. BET surface area study

Fig. 9a and b show the typical nitrogen adsorption–desorption isotherms for the pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite samples, respectively. The specific surface area is calculated according to the Brunauer–Emmett–Teller (BET) equation.³⁶

$$\frac{1}{V \left[\left(\frac{p_0}{p} \right) - 1 \right]} = \frac{1}{V_m C} + \frac{1}{V_m C \left(\frac{p}{p_0} \right)} \quad (4)$$

where V is the amount of gas adsorbed, V_m is the amount of maximal monolayer adsorption and C is the BET constant, and P and p_0 are the equilibrium and saturation pressures at the temperature of adsorption. The calculated BET surface area for the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample, $18.83 \text{ m}^2 \text{ g}^{-1}$ shows an increment from the pristine sample, $12.93 \text{ m}^2 \text{ g}^{-1}$ which is probably caused by the presence of rGO and/or by the formation of Bi_2S_3 nanostrips.

3.8. Electrochemical study

The electrochemical studies were performed using a three-electrode cell configuration set-up where the as-synthesized pristine Bi_2S_3 and all the $\text{Bi}_2\text{S}_3@r\text{GO}$ nanocomposite samples were separately studied as the working electrodes. The electrode fabrication technique is already elaborated in the characterization section. Fig. 10a and b represent the CV curves of the pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ samples at scan rate $5\text{--}100 \text{ mV s}^{-1}$ within a potential range of -0.85 to -0.2 V in 6 M KOH electrolyte. CV curves in Fig. 10a and b show the well-resolved redox peaks indicating the capacitance characteristics are mainly governed by faradaic redox reactions. Moreover, compared with pristine Bi_2S_3 , $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite exhibits relatively larger current responses at the same scan rates, showing higher capacitance. The redox peaks for $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ are symmetric at the scan rate of 1 mV s^{-1} , indicating good redox reactions. However, the minor shift in the

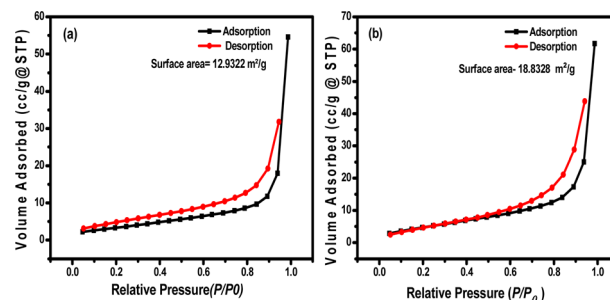


Fig. 9 BET surface area measurement analysis for, (a) pristine Bi_2S_3 , and (b) $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample.



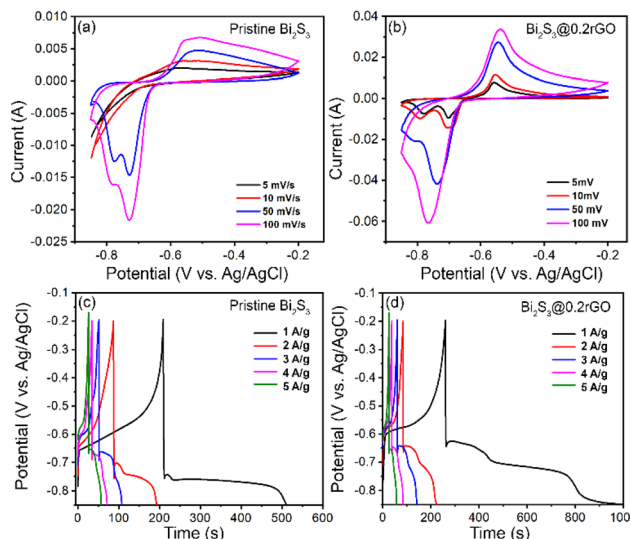


Fig. 10 Electrochemical performance study. CV curves of (a) pristine Bi_2S_3 and (b) $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ at different scan rates. GCD curves of (c) pristine Bi_2S_3 , (d) $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite at 1 to 5 A g^{-1} .

oxidation and reduction peaks in Fig. 10b with an increase in scan rate implies the irreversibility of the redox reaction in the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample. The possible reaction mechanism between Bi_2S_3 and the OH^- ions in the KOH electrolyte is as follows:³⁷



Fig. 10c and d shows the GCD curves of the pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite samples at different current densities (1–5 A g^{-1}) in the range of -0.85 to -0.2 V.

GCD curves depict the non-linear discharge curves with multiple segments for both samples at various current densities. Interestingly, the $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite sample displays a longer plateau at a lower current density (A g^{-1}) than pristine Bi_2S_3 , indicating a higher capacitance value. During discharging, a sharp potential drop is observed at first which is related to the internal resistance of the active material, then follows a prolonged discharge plateau associated with the pseudocapacitive behavior of the electrode.³⁸ The specific capacitance values were calculated from the respective discharge curves using the following equation:

$$C_{\text{sp}} = (I \times \Delta t) / (m \times \Delta V) \quad (6)$$

where, I -discharge current density in A, Δt -discharge time in s, m -mass of material in g, and ΔV -potential window in V. The maximum specific capacitance obtained for the pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite samples were calculated as 266 and 705 F g^{-1} , respectively, at the current density of 1 A g^{-1} . CV and GCD curves of other $\text{Bi}_2\text{S}_3@r\text{GO}$ nanocomposite materials shown in Fig. S5 and S6,† show well-defined redox peaks at high scan rates indicating characteristics of pseudocapacitor behaviour. The measured specific capacitance values for other

composites at 1 A g^{-1} are 613 ($\text{Bi}_2\text{S}_3@0.4\text{rGO}$) F g^{-1} and 356 F g^{-1} ($\text{Bi}_2\text{S}_3@0.8\text{rGO}$) (Fig. S6, in the ESI†). It is clear from Fig. 10c and d that specific capacitance gradually decreases for both the samples with the increase of current density this may be because, at higher current densities, resistance enhances and does not get enough time for the faradaic redox reaction to occur between the electrode surface and the electrolyte. Fig. 11a shows the Nyquist plots of pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite samples at frequency 0.01 Hz to 1 MHz, respectively. The observed Nyquist plots show a small depressed semicircle in the high-frequency region and a near-vertical line in the low-frequency region.

Nyquist plots show less semi-circular curves leading to obtained lesser charge-transfer resistance that is favorable for supercapacitor materials. The mass and charge transfer areas can be identified by a straight line in the low-frequency region and a quasi-semicircle in the high-frequency region. Amongst the prepared nanocomposites, $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ possesses the largest slope, which infers that it has the lowest Warburg impedance. Fig. 11b compares the cycle performances of the pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite samples at the current density of 1 A g^{-1} . Between both the samples, $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ confirms the good cycle performance with a capacitance retention of 81% after 1000 cycles, whereas the pristine Bi_2S_3 possesses 76% capacity retention after 1000 cycles.

The results obtained are in good agreement with the previously reported results.^{7,28} Table 1 shows a comparison between the electrochemical performances of the as-synthesized $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite with the previously reported data. It is to be noted that the present work showed excellent electrochemical performance even for a very small amount (0.2%) of GO in the nanocomposite, as compared to the earlier report, which as more than 15% rGO (Table 1). The better electrochemical performance for $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ is attributed to the increased effective surface area and the synergistic relation between rGO and Bi_2S_3 . Fig. S7† illustrates the synergistic interaction between rGO and Bi_2S_3 .

As depicted in the figure, the CV curve of $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ at a scan rate of 50 mV s^{-1} displays distinct redox peaks when compared to the GO and pristine Bi_2S_3 counterparts, indicating efficient electron transfer within the materials.

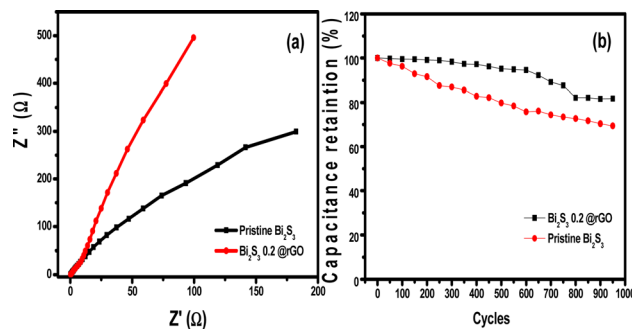


Fig. 11 (a) Nyquist plots of pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ (b) Cyclic stability of the pristine Bi_2S_3 and $\text{Bi}_2\text{S}_3@0.2\text{rGO}$ nanocomposite at 1 A g^{-1} .



Table 1 Comparison of the synthesis process, morphology, and electrochemical properties of some chosen materials reported in the literature with the present work

Sr. no.	Electrode materials	Bi ₂ S ₃ /rGO wt%	Synthesis method	Morphology	Specific capacitance (at 1 A g ⁻¹)	Stability cycles	Ref.
1	Bi ₂ S ₃ -rGO	32%	Hydrothermal	Nanorods	396 F g ⁻¹	100	7
2	Bi ₂ S ₃ /FGS	16%	Hydrothermal	Nanosheets	292 F g ⁻¹	5000	29
3	Bi ₂ S ₃	Nil	Solvothermal	Hollow microtubes	532 F g ⁻¹	3000	15
4	Bi ₂ S ₃	Nil	Solvothermal	—	432 F g ⁻¹	1000	39
5	Bi ₂ S ₃	Nil	Solvothermal	Nanoparticles	342 F g ⁻¹	500	37
6	Bi ₂ S ₃ /rGO	2%	One pot precipitation	Nanorods	290 F g ⁻¹	500	28
7	Bi ₂ S ₃ /C-3	24%	Hydrothermal	Nanospheres	419 F g ⁻¹	—	40
8	sg-C ₃ N ₄ /Bi ₂ S ₃	43%	Coprecipitation/calcination	Porous morphology	670 F g ⁻¹	3000	41
9	Bi ₂ S ₃ /rGO	0.18%	Solid state	Nanostrips	705 F g ⁻¹	1000	This work

4. Conclusion

In summary, we present a scalable one-pot solid-state method for the preparation of Bi₂S₃@rGO nanocomposites designed for supercapacitor applications. The process involves a low-temperature diffusion-controlled growth of an orthorhombic crystal habit featuring the 2D nanostrip morphology of the as-synthesized Bi₂S₃ particles. The incorporation of rGO enhances the effective surface area and establishes a synergistic relationship with Bi₂S₃ nanostrips. The nanocomposite materials after synthesis, were consecutively processed and applied as the working electrode for conducting the CV, GCD, and EIS measurements. The superior specific capacitance (705 F g⁻¹ at 1 A g⁻¹), excellent cyclic stability, and significant capacitance retention (81%) validate the suitability of the fabricated Bi₂S₃@0.2rGO nanocomposites as electrode material for supercapacitor applications.

Author contributions

(1) Vijay B Autade-performed experiments, analysed data, data interpretation, writing the paper. (2) Kaustav Bhattacharjee-design of experiments, analysis of results, writing the paper. (3) Ranjit S. Kate-analysed data, data interpretation, writing the paper. (4) Sudhir S. Arbuj-resources for characterization. (5) Sanjay K. Apte-conceptualization and supervision. (6) Ramchandra S. Kalubarme – resources for characterization. (7) Bharat B. Kale – investigation, writing the draft, editing. (8) Sandeep A. Arote – research and data interpretation, editing, overall supervision.

Conflicts of interest

“There are no conflicts to declare”.

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